

Abstract of the Disclosure

An example photoelectric conversion device includes a first insulating layer that is formed so as to cover a photoelectric conversion element and a connection electrode. The first insulating layer has an opening portion extending to the connection electrode. A conductive layer is formed on the first insulating layer. The conductive layer is formed so as to be connected via the opening portion to the connection electrode. The connection electrode may be provided in a periphery of an active area.